Transistors Panasonic

2SD1820

Silicon NPN epitaxial planar type

For general amplification Complementary to 2SB1219

■ Features

- ullet Low collector-emitter saturation voltage $V_{\text{CE(sat)}}$
- S-Mini type package, allowing downsizing of the equipment and automatic insertion through the tape packing.

■ Absolute Maximum Ratings $T_a = 25$ °C

Parameter	Symbol	Rating	Unit	
Collector-base voltage (Emitter open)	V_{CBO}	30	V	
Collector-emitter voltage (Base open)	V _{CEO}	25	V	
Emitter-base voltage (Collector open)	V_{EBO}	5	V	
Collector current	I_{C}	500	mA	
Peak collector current	I _{CP}	1	A	
Collector power dissipation	P _C	150	mW	
Junction temperature	T _j	150	°C	
Storage temperature	T _{stg}	-55 to +150	°C	

■ Package

- Code SMini3-G1
- Pin Name
 - 1. Base
 - 2. Emitter
 - 3. Collector
- Marking Symbol: W

■ Electrical Characteristics T_a = 25°C±3°C

a)			
Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Collector-base voltage (Emitter open)	V _{CBO}	$I_{\rm C} = 10 \mu{\rm A}, I_{\rm E} = 0$	30			V
Collector-emitter voltage (Base open)	V _{CEO}	$I_C = 2 \text{ mA}, I_B = 0$	25			V
Emitter-base voltage (Collector open)	V _{EBO}	$I_{\rm E} = 10 \mu \text{A}, I_{\rm C} = 0$	5			V
Collector-base cutoff current (Emitter open)	I_{CBO}	$V_{CB} = 20 \text{ V}, I_{E} = 0$			0.1	μА
Forward current transfer ratio *1	h _{FE1} *2	$V_{CE} = 10 \text{ V, } I_{C} = 150 \text{ mA}$	85		340	
	h _{FE2}	$V_{\rm CE} = 10 \text{ V}, I_{\rm C} = 500 \text{ mA}$	40			
Collector-emitter saturation voltage *1	V _{CE(sat)}	$I_C = 300 \text{ mA}, I_B = 30 \text{ mA}$		0.35	0.60	V
Transition frequency	$\mathcal{O}_{\mathrm{f_T}}$	$V_{CB} = 10 \text{ V}, I_{E} = -50 \text{ mA}, f = 200 \text{ MHz}$		200		MHz
Collector output capacitance	C_{ob}	$V_{CR} = 10 \text{ V}, I_F = 0, f = 1 \text{ MHz}$		6	15	pF
(Common base, input open circuited)	ob	VCB 10 V, 1E 0, 1 - 1 WILL			13	h.

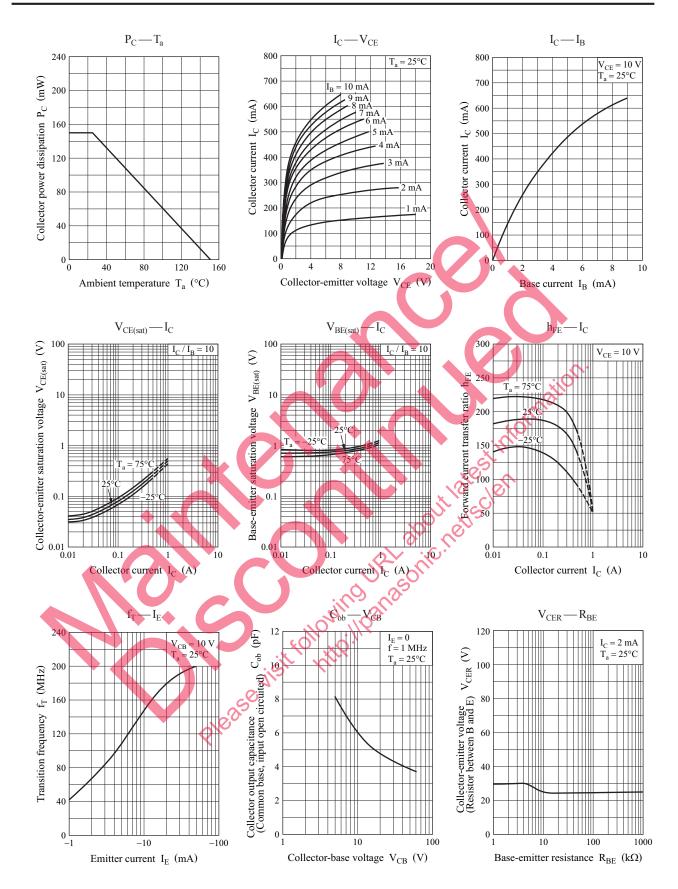
Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.

- 2. *1: Pulse measurement
 - *2: Rank classification

Rank	Q	R	S	No-rank
h_{FE1}	85 to 170	120 to 240	170 to 340	85 to 340
Marking symbol	WQ	WR	WS	_

Product of no-rank is not classified and have no marking symbol for rank.

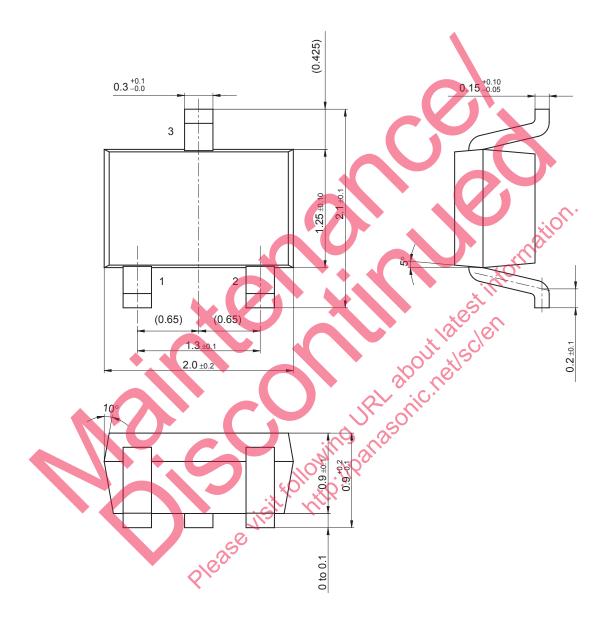
2SD1820 Panasonic



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Panasonic 2SD1820

SMini3-G1 Unit: mm



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